

SOT23 PNP SILICON PLANAR SMALL SIGNAL TRANSISTORS

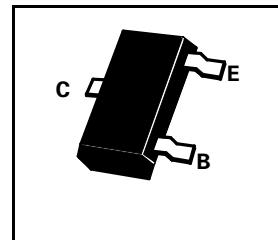
BCW61

ISSUE 2 – FEBRUARY 95

PART MARKING DETAIL –

| | | | |
|--------|------|---------|------|
| BCW61A | - BA | BCW61AR | - CA |
| BCW61B | - BB | BCW61BR | - CB |
| BCW61C | - BC | BCW61CR | - CC |
| BCW61D | - BD | BCW61DR | - CD |

COMPLEMENTARY TYPE – BCW60

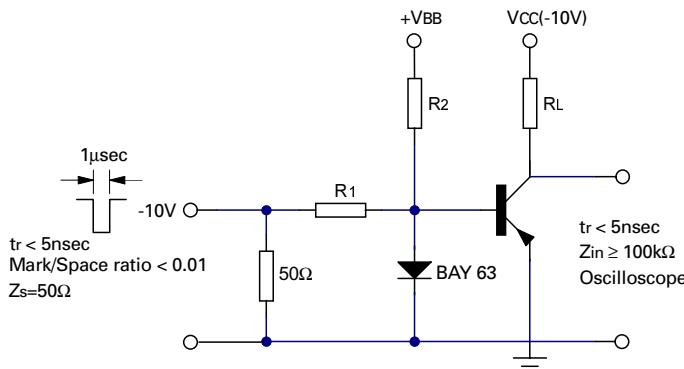


ABSOLUTE MAXIMUM RATINGS.

| PARAMETER | SYMBOL | | | VALUE | | | UNIT |
|---|----------------|--|--|-------------|--|--|------|
| Collector-Base Voltage | V_{CBO} | | | -32 | | | V |
| Collector-Emitter Voltage | V_{CEO} | | | -32 | | | V |
| Emitter-Base Voltage | V_{EBO} | | | -5 | | | V |
| Continuous Collector Current | I_C | | | -200 | | | mA |
| Base Current | I_B | | | -50 | | | mA |
| Power Dissipation at $T_{amb}=25^\circ\text{C}$ | P_{TOT} | | | 330 | | | mW |
| Operating and Storage Temperature Range | $T_j; T_{stg}$ | | | -55 to +150 | | | °C |

FOUR TERMINAL NETWORK DATA ($I_C=2\text{mA}$, $V_{CE}=5\text{V}$, $f=1\text{kHz}$)

| | h _{FE} Group A | | | h _{FE} Group B | | | h _{FE} Group C | | | h _{FE} Group D | | | |
|-----------|-------------------------|------|------|-------------------------|------|------|-------------------------|------|------|-------------------------|------|------|-----------|
| | Min. | Typ. | Max. | |
| h_{11e} | 1.6 | 2.7 | 4.5 | 2.5 | 3.6 | 6.0 | 3.2 | 4.5 | 8.5 | 4.5 | 7.5 | 12 | kΩ |
| h_{12e} | | 1.5 | | | 2 | | | 2 | | | 3 | | 10^{-4} |
| h_{21e} | | 200 | | | 260 | | | 330 | | | 520 | | |
| h_{22e} | | 18 | 30 | | 24 | 50 | | 30 | 60 | | 50 | 100 | μS |



BCW61

ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^\circ C$ unless otherwise stated).

| PARAMETER | SYMBOL | MIN. | TYP. | MAX. | UNIT | CONDITIONS. |
|---|---|----------------|------------------------------------|----------------|----------------------------------|---|
| Collector-Emitter Breakdown Voltage | $V_{(BR)CEO}$ | -32 | | | V | $I_{CEO}=2mA$ |
| Emitter-Base Breakdown Voltage | $V_{(BR)EBO}$ | -5 | | | V | $I_{EBO}=1\mu A$ |
| Collector-Emitter Cut-off Current | I_{CES} | | | -20 -20 | nA μA | $V_{CES}=-32V$ $V_{CES}=-32V, T_{amb}=150^\circ C$ |
| Emitter-Base Cut-Off Current | I_{EBO} | | | -20 | nA | $V_{EBO}=-4V$ |
| Collector-Emitter Saturation Voltage | $V_{CE(sat)}$ | | -0.12 -0.25 | -0.25 -0.55 | V V | $I_C=10mA, I_B= -0.25mA$ $I_C=50mA, I_B= -1.25mA$ |
| Base-Emitter Saturation Voltage | $V_{BE(sat)}$ | -0.60 -0.68 | -0.70 -0.80 | -0.85 -1.05 | V V | $I_C=-10mA, I_B=-0.25mA$ $I_C=-50mA, I_B=-1.25mA$ |
| Base - Emitter Voltage | V_{BE} | -0.6 | -0.55 -0.65 -0.72 | -0.75 | V V V | $I_C=10\mu A, V_{CE}=-5V$ $I_C=2mA, V_{CE}=-5V$ $I_C=50mA, V_{CE}=-1V$ |
| Static Forward Current Transfer Ratio | BCW61A | h_{FE} | 120 60 | 140 170 | 220 | $I_C=10\mu A, V_{CE}=-5V$ $I_C=2mA, V_{CE}=-5V$ $I_C=50mA, V_{CE}=-1V$ |
| | BCW61B | | 30 180 80 | 200 250 | 310 | $I_C=10\mu A, V_{CE}=-5V$ $I_C=2mA, V_{CE}=-5V$ $I_C=50mA, V_{CE}=-1V$ |
| | BCW61C | | 40 250 100 | 270 350 | 460 | $I_C=10\mu A, V_{CE}=-5V$ $I_C=2mA, V_{CE}=-5V$ $I_C=50mA, V_{CE}=-1V$ |
| | BCW61D | | 100 380 110 | 340 500 | 630 | $I_C=10\mu A, V_{CE}=-5V$ $I_C=2mA, V_{CE}=-5V$ $I_C=50mA, V_{CE}=-1V$ |
| Transition Frequency | f_T | | 180 | | MHz | $I_C=10mA, V_{CE}=-5V$ $f = 100MHz$ |
| Emitter-Base Capacitance | C_{ebo} | | 11 | | pF | $V_{EBO}=-0.5V, f=1MHz$ |
| Collector-Base Capacitance | C_{cbo} | | | 6 | pF | $V_{CBO}=-10V, f=1MHz$ |
| Noise Figure | N | | 2 | 6 | dB | $I_C=-0.2mA, V_{CE}=-5V$ $R_G=2K\Omega, f=1KHz$ $\Delta f=200Hz$ |
| Switching times: Delay Time Rise Time Turn-on Time Storage Time Fall Time Turn-Off Time | t_d t_r t_{on} t_s t_f t_{off} | | 35 50 85 400 80 480 | 150 | ns ns ns ns ns ns | $-I_C: -I_{B1}: I_{B2} = 10:1:1mA$ $R_1=R_2=5K\Omega$ $V_{BB}=-3.6V, R_L=990\Omega$ |

*Measured under pulsed conditions. Pulse width=300μs. Duty cycle Spice parameter data is available upon request for this device